

RF2436

TRANSMIT/RECEIVE SWITCH

RoHS Compliant & Pb-Free Product Package Style: SOT-5

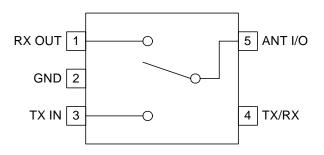


Features

- Single Positive Power Supply
- Low Current Consumption
- 1dB Insertion Loss at 900MHz
- 24 dB Crosstalk Isolation at 900 MHz
- +27 dBm Output P1dB

Applications

- Cordless Phones
- Wireless Computer Peripherals
- Wireless Security Systems
- General Purpose RF Switching
- Commercial and Consumer Systems



Functional Block Diagram

Product Description

The RF2436 is a very low-cost transmit/receive GaAs MESFET switch. The device can handle power levels as high as +28dBm and spans a frequency range from DC to 2500MHz. The switch will operate from power supply voltages as low as 1.5V and as high as 6V with a CMOS logic driver for the control input. No negative voltage is required, and current consumption is very low. VSWR for the active channel (transmit or receive) is 1.1:1. The device is housed in a very small industry-standard SOT 5-lead plastic package.

Ordering Information

RF2436 Transmit/Receive Switch
RF2436PCBA-41X Fully Assembled Evaluation Board

Optimum Technology Matching® Applied

☐ GaAs HBT ✓ GaAs MESFET	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
▼ GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT	

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Rev A6 DS080128

RF2436



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	0 to +8.0	V _{DC}
Control Voltage	-1.0 to +6.0	V
Input RF Power	+30	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

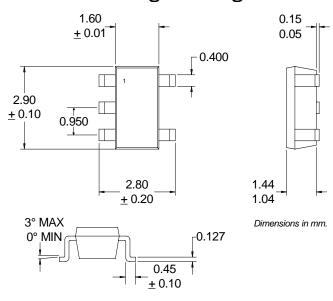
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Parameter	Specification		Unit	Condition		
raidilletei	Min.	Тур.	Max.	Offic	Condition	
Overall					T=25 °C, V _{DD} =3.0V, Freq=900MHz	
Frequency Range		DC to 2500		MHz		
Insertion Loss		1	2	dB	Transmit or receive mode.	
Isolation	20	22		dB	Receive mode; ANT I/O to TX IN crosstalk	
	20	24		dB	Transmit mode; ANT I/O to RXOUT crosstalk	
RX OUT VSWR		1.1:1			Receive mode.	
TX IN VSWR		1.1:1			Transmit mode.	
Output P1dB		+27		dBm		
Output IP3		+39		dBm		
Control Logic						
CTRL Logic "Low" Voltage		0		V	Receive mode.	
CTRL Logic "High" Voltage		0.7		V	Transmit mode.	
Power Supply						
Voltage		3		V	Specifications	
		1.5 to 6		V	Operating Limits	
Current		5	10	μА	Receive mode.	
		0.5	1	mA	Transmit mode.	

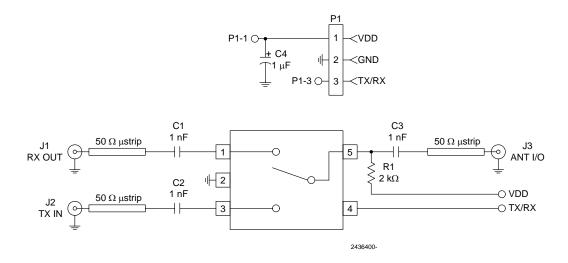


Pin	Function	Description	Interface Schematic
1	RX OUT	Output pin for Receive mode. VSWR is 1.1:1 when Receive mode is selected and highly capacitive when Transmit mode is selected.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to the ground plane.	
3	TX IN	Input pin for Transmit mode. The input VSWR is 1.1:1 when Transmit mode is selected and highly capacitive when Receive mode is selected.	
4	TX/RX	Transmit Mode/Receive Mode control pin. A "low" level chooses Receive mode; a "high" level chooses Transmit mode. CMOS logic may be used to drive the control input.	
5	ANT I/O	Input/Output pin from/to antenna and power supply pin. This pin must be biased with VDD through a resistor.	

Package Drawing

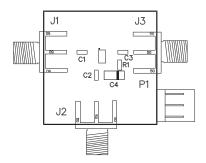


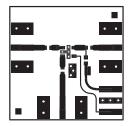
Evaluation Board Schematic



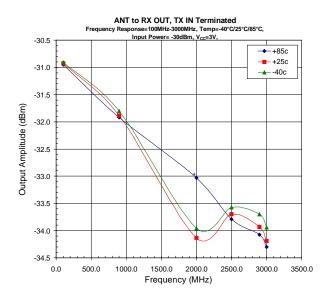


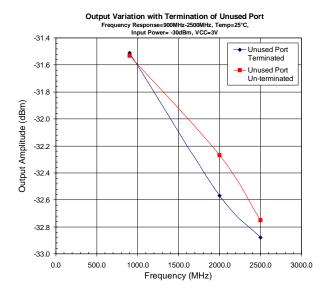
Evaluation Board Layout











RoHS* Banned Material Content

RoHS Compliant:

Package total weight in grams (g):

Compliance Date Code:

Bill of Materials Revision:

Pb Free Category:

Yes

0.008

518

Bill of Materials	Parts Per Million (PPM)					
	Pb	Cd	Hg	Cr VI	PBB	PBDE
Die	0	0	0	0	0	0
Molding Compound	0	0	0	0	0	0
Lead Frame	0	0	0	0	0	0
Die Attach Epoxy	0	0	0	0	0	0
Wire	0	0	0	0	0	0
Solder Plating	0	0	0	0	0	0

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted above.

^{*} DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

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